

# DL-3147-021

# Index Guided AlGaInP Laser Diode

#### Overview

DL-3147-021 is index guided 645 nm (Typ.) AlGaInP laser diode with low threshold current. The low threshold current is achieved by a strained multiple quantum well active layer. DL-3147-021 is suitable for laser pointer.

#### **Features**

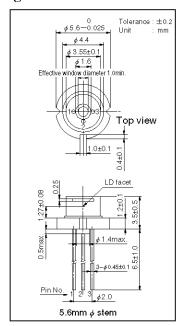
· Short wavelength : 645 nm (Typ.) · Low threshold current : Ith =  $30 \,\mathrm{mA}$  (Typ.) · Low operating voltage : Vop = 2.3 V (Typ.)

· Small package : 5.6 mm  $\phi$ 

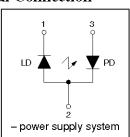
## Absolute Maximum Ratings at Tc=25 $^{\circ}$ C

Parameter		Symbol	Ratings	Unit	
Light Output		Po	5	mW	
Reverse Voltage	Laser PIN	Vr	2 30	V	
Operating Temperature		Topr	-10 to +40	$^{\circ}\!\mathbb{C}$	
Storage Temperature		Tstg	-40 to +85	$^{\circ}\mathbb{C}$	

### **Package Dimensions**



#### **Electrical Connection**



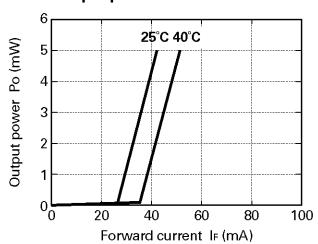
## Electrical and Optical Characteristics at Tc=25 $^{\circ}$ C

Parai	neter	Symbol	Condition	Min.	Тур.	Max.	Unit
Threshol	d Current	Ith	CW	_	30	50	mA
Operating	g Current	Iop	Po=5mW	_	45	60	mA
Operating	g Voltage	Vop	Po=5mW	_	2.3	2.6	V
Lasing W	avelength	λp	Po=5mW	_	645	660	nm
Beam 💥 )	Perpendicular	$\theta \perp$	Po=5mW	25	30	40	deg.
Divergence	Parallel	θ //	Po=5mW	6	7.5	10	deg.
Off Axis	Perpendicular	$\Delta \theta \perp$	_	_	_	±3	deg.
Angle	Parallel	$\Delta  heta$ //	_	_	_	±3	deg.
Differential	Efficiency	dPo/dIop	_	0.2	0.4	0.8	mW/mA
Monitoring O	utput Current	Im	Po=5mW	0.15	0.4	0.75	mA
Astign	natism	As	Po=5mW	_	8	_	μm

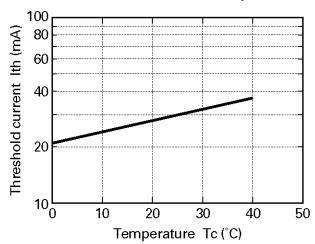
💥) Full angle at half maximum note: The above product specifications are subject to change without notice.

#### Characteristics

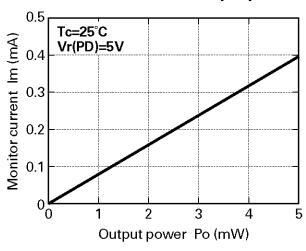




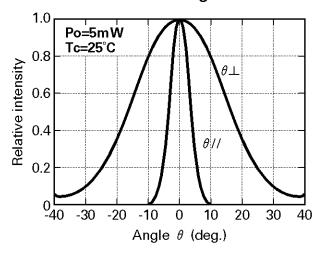
## Threshold current vs. Temperature



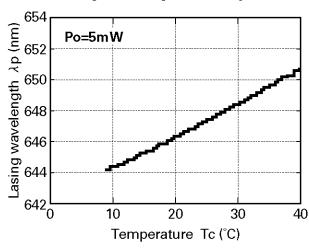
## Monitor current vs. Output power



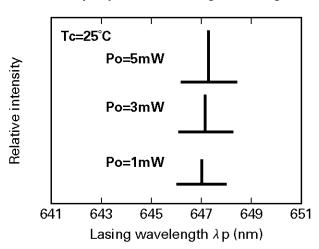
## Beam divergence



## Lasing wavelength vs. Temperature



## Output power vs. Lasing wavelength





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# Precautionary instructions in handling gallium arsenic products

Special precautions must be taken in handling this product because it contains, gallium arsenic, which is designated as a toxic substance by law. Be sure to adhere strictly to all applicable laws and regulations enacted for this substance, particularly when it comes to disposal.

Manufactured by; Tottori SANYO Electric Co., Ltd.

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